



## Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

MAX308/MAX309

### General Description

The MAX308/MAX309 precision, monolithic, CMOS analog multiplexers (muxes) offer low on-resistance (less than  $100\Omega$ ), which is matched to within  $5\Omega$  between channels and remains flat over the specified analog signal range ( $7\Omega$  max). They also offer low leakage over temperature (NO-off leakage current less than  $5nA$  at  $+85^\circ C$ ) and fast switching speeds (transition time less than  $250ns$ ). The MAX308 is a single-ended 1-of-8 device, and the MAX309 is a differential 2-of-4 device.

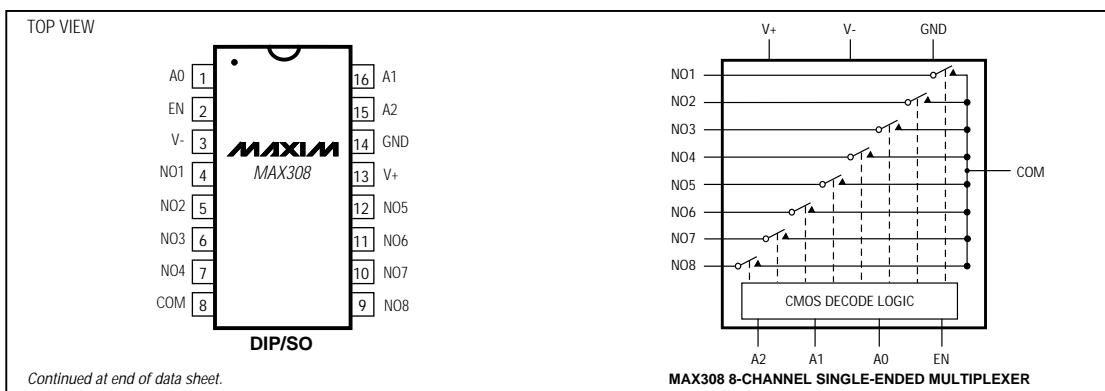
The MAX308/MAX309 are fabricated with Maxim's improved 44V silicon-gate process. Design improvements yield extremely low charge injection (less than  $10pC$ ) and guarantee electrostatic discharge protection greater than 2000V.

These muxes operate with a single  $+4.5V$  to  $+30V$  supply or bipolar  $\pm 4.5V$  to  $\pm 20V$  supplies, while retaining TTL/CMOS-logic input compatibility and fast switching. CMOS inputs provide reduced input loading. These improved parts are plug-in upgrades for the industry-standard DG408, DG409, DG508A, and DG509A.

### Applications

- Sample-and-Hold Circuits
- Automatic Test Equipment
- Heads-Up Displays
- Guidance and Control Systems
- Military Radios
- Communications Systems
- Battery-Operated Systems
- PBX, PABX
- Audio Signal Routing

### Pin Configurations/Functional Diagrams/Truth Tables



Maxim Integrated Products 1

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## ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-	
V+	-0.3V, 44V
GND	-0.3V, 25V
Digital Inputs, NO, COM (Note 1)	(V- - 2V) to (V+ + 2V) or 30mA, (whichever occurs first)
Continuous Current (any terminal)	30mA
Peak Current, NO or COM (pulsed at 1ms, 10% duty cycle max)	100mA

Continuous Power Dissipation (TA = +70°C)	
Plastic DIP (derate 10.53mW/°C above +70°C)	842mW
Narrow SO (derate 8.70mW/°C above +70°C)	696mW
CERDIP (derate 10.00mW/°C above +70°C)	800mW
Operating Temperature Ranges	
MAX30_C	0°C to +70°C
MAX30_E	-40°C to +85°C
MAX30_MJE	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

**Note 1:** Signals on NO, COM, EN, A0, A1, or A2 exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +15V, V- = -15V, GND = 0V, VAH = +2.4V, VAL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	(Note 2)	UNITS
<b>SWITCH</b>									
Analog Signal Range	VNO, VCOM	(Note 3)				-15	15		V
On-Resistance	RON	I <sub>NO</sub> = -1.0mA, V <sub>COM</sub> = ±10V	TA = +25°C		60	100			Ω
			TA = T <sub>MIN</sub> to T <sub>MAX</sub>			125			
On-Resistance Matching Between Channels	ΔRON	I <sub>NO</sub> = -1.0mA, V <sub>COM</sub> = ±10V (Note 4)	TA = +25°C		1.5	5			Ω
			TA = T <sub>MIN</sub> to T <sub>MAX</sub>			8			
On-Resistance Flatness	R <sub>FLAT</sub>	I <sub>NO</sub> = -1.0mA, V <sub>COM</sub> = ±5V or 0V	TA = +25°C		1.8	7			Ω
			TA = T <sub>MIN</sub> to T <sub>MAX</sub>			10			
NO-Off Leakage Current (Note 5)	I <sub>NO(OFF)</sub>	V <sub>COM</sub> = ±10V, V <sub>NO</sub> = ±10V, V <sub>EN</sub> = 0V	TA = +25°C		-0.5	0.01	0.5		nA
			TA = T <sub>MIN</sub> to T <sub>MAX</sub>	C, E	-2.5		2.5		
COM-Off Leakage Current (Note 5)	I <sub>COM(OFF)</sub>	V <sub>NO</sub> = ±10V, V <sub>COM</sub> = ±10V, V <sub>EN</sub> = 0V	MAX308	TA = +25°C	-0.75	0.02	0.75		nA
				TA = T <sub>MIN</sub> to T <sub>MAX</sub>	C, E	-10	10		
COM-On Leakage Current (Note 5)	I <sub>COM(ON)</sub>	V <sub>NO</sub> = ±10V, V <sub>COM</sub> = ±10V, V <sub>EN</sub> = 0V sequence each switch on	MAX308 MAX309	TA = +25°C	-0.75	0.02	0.75		nA
				TA = T <sub>MIN</sub> to T <sub>MAX</sub>	C, E	-5	5		
			MAX309	TA = +25°C	-0.75	0.02	0.75		nA
				TA = T <sub>MIN</sub> to T <sub>MAX</sub>	C, E	-10	10		

# Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

## ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

( $V_+ = +15V$ ,  $V_- = -15V$ ,  $GND = 0V$ ,  $V_{AH} = +2.4V$ ,  $V_{AL} = +0.8V$ ,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
<b>INPUT</b>							
Input Current with Input Voltage High	I <sub>AH</sub>	$V_A = 2.4V$ or $15V$		-1.0	1.0	1.0	$\mu A$
Input Current with Input Voltage Low	I <sub>AL</sub>	$V_{EN} = 0V$ or $2.4V$ , $V_A = 0V$		-1.0	1.0	1.0	$\mu A$
<b>SUPPLY</b>							
Power-Supply Range				$\pm 4.5$	$\pm 20$	$\pm 20$	V
Positive Supply Current	I <sub>+</sub>	$V_{EN} = V_A = 0V$ or $4.5V$		$T_A = +25^\circ C$	16	30	$\mu A$
				$T_A = T_{MIN}$ to $T_{MAX}$		75	
Negative Supply Current	I <sub>-</sub>	$V_{EN} = 2.4V$ , $V_{A(ALL)} = 0V$ or $2.4V$		$T_A = +25^\circ C$	0.075	0.5	mA
				$T_A = T_{MIN}$ to $T_{MAX}$			
<b>DYNAMIC</b>							
Transistion Time	t <sub>TRANS</sub>	Figure 2		$T_A = +25^\circ C$	85	175	ns
				$T_A = T_{MIN}$ to $T_{MAX}$		250	
Break-Before-Make Interval	t <sub>OPEN</sub>	Figure 4		$T_A = +25^\circ C$	10	40	ns
				$T_A = +25^\circ C$	85	150	
Enable Turn-On Time	t <sub>ON(EN)</sub>	Figure 3		$T_A = +25^\circ C$		225	ns
				$T_A = T_{MIN}$ to $T_{MAX}$			
Enable Turn-Off Time	t <sub>OFF(EN)</sub>	Figure 3		$T_A = +25^\circ C$		150	ns
				$T_A = T_{MIN}$ to $T_{MAX}$		300	
Charge Injection (Note 3)	Q	$C_L = 1.0nF$ , $V_{NO} = 0V$ , $R_S = 0\Omega$ , Figure 5		$T_A = +25^\circ C$	2	10	pC
				$T_A = T_{MIN}$ to $T_{MAX}$			
Off Isolation (Note 6)	V <sub>ISO</sub>	$V_{EN} = 0V$ , $R_L = 1k\Omega$ , $f = 100kHz$ , Figure 6		$T_A = +25^\circ C$		-75	dB
Crosstalk Between Channels	V <sub>CT</sub>	$V_{EN} = 2.4V$ , $f = 100kHz$ , $V_{GEN} = 1V_{P,P}$ , $R_L = 1k\Omega$ , Figure 7		$T_A = +25^\circ C$		-92	dB
Logic Input Capacitance	C <sub>IN</sub>	$f = 1MHz$		$T_A = +25^\circ C$	8	8	pF
NO-Off Capacitance	C <sub>NO(OFF)</sub>	$f = 1MHz$ , $V_{EN} = V_{NO} = 0V$ , Figure 8		$T_A = +25^\circ C$	3	3	pF
COM-Off Capacitance	C <sub>COM(OFF)</sub>	$f = 1MHz$ , $V_{EN} = 0.8V$ , $V_{COM} = 0V$ , Figure 8	MAX308	$T_A = +25^\circ C$	26	26	pF
			MAX309		14	14	
COM-On Capacitance	C <sub>COM(ON)</sub>	$f = 1MHz$ , $V_{EN} = 2.4V$ , $V_{COM} = 0V$ , Figure 8	MAX308	$T_A = +25^\circ C$	37	37	pF
			MAX309		25	25	

# Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

## ELECTRICAL CHARACTERISTICS—Single Supply

(V<sub>+</sub> = +12V, V<sub>-</sub> = 0V, GND = 0V, V<sub>AH</sub> = +2.4V, V<sub>AL</sub> = +0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
<b>SWITCH</b>							
Analog Signal Range	V <sub>NO</sub> , V <sub>COM</sub>	(Note 3)		0	12	12	V
On-Resistance	R <sub>ON</sub>	I <sub>NO</sub> = -1.0mA V <sub>COM</sub> = 3V or 10V	T <sub>A</sub> = +25°C	120	175	175	Ω
<b>DYNAMIC</b>							
Transition Time (Note 3)	t <sub>TRANS</sub>	V <sub>NO1</sub> = 8V, V <sub>NO8</sub> = 0V, V <sub>IN</sub> = 2.4V, Figure 2	T <sub>A</sub> = +25°C	115	450	450	ns
Enable Turn-On Time (Note 3)	t <sub>ON(EN)</sub>	V <sub>INH</sub> = 2.4V, V <sub>INL</sub> = 0V, V <sub>NO1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C	100	600	600	ns
Enable Turn-Off Time (Note 3)	t <sub>OFF(EN)</sub>	V <sub>INH</sub> = 2.4V, V <sub>INL</sub> = 0V, V <sub>NO1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C	75	300	300	ns
Charge Injection (Note 3)	Q	C <sub>L</sub> = 1.0nF, V <sub>NO</sub> = 0V, R <sub>S</sub> = 0Ω	T <sub>A</sub> = +25°C	2	10	10	pC

**Note 2:** The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

**Note 3:** Guaranteed by design.

**Note 4:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ . On-resistance match between channels and flatness are guaranteed only with specified voltages. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured at the extremes of the specified analog signal range.

**Note 5:** Leakage parameters are 100% tested at the maximum rated hot temperature and guaranteed by correlation at +25°C.

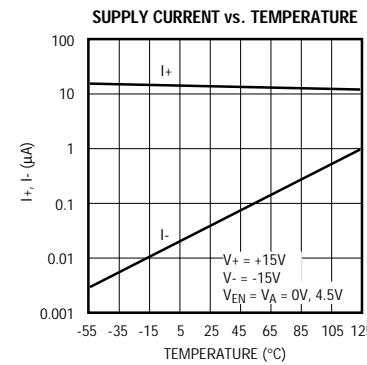
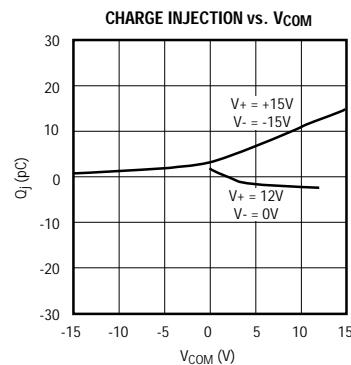
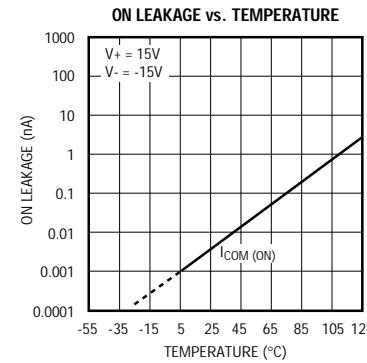
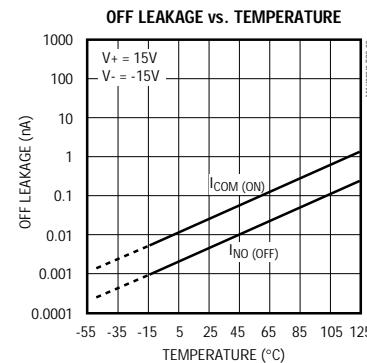
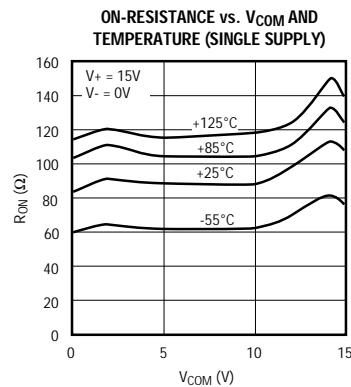
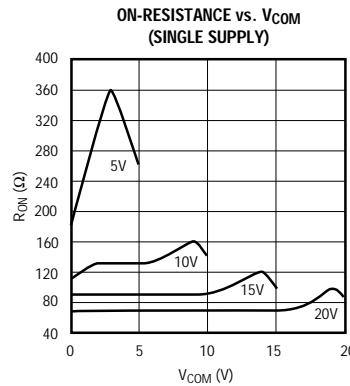
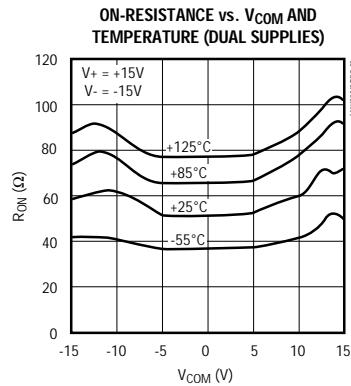
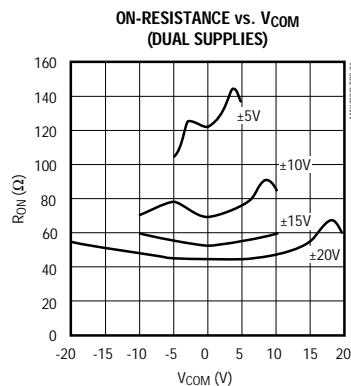
**Note 6:** Off isolation =  $20\log V_{COM}/V_{NO}$ , where V<sub>COM</sub> = output and V<sub>NO</sub> = input to off switch.

# Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

## Typical Operating Characteristics

( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

**MAX308/MAX309**



**MAXIM**

# Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

## Pin Description

PIN		NAME	FUNCTION
MAX308	MAX309		
1, 15, 16	—	A0, A2, A1	Address Inputs
—	1, 16	A0, A1	Address Inputs
2	2	EN	Enable Input
3	3	V-	Negative Supply Voltage Input
4-7	—	NO1-NO4	Analog Inputs—bidirectional
—	4-7	NO1A-NO4A	Analog Inputs—bidirectional
8	—	COM	Analog Output—bidirectional
—	8, 9	COMA, COMB	Analog Outputs—bidirectional
9-12	—	NO8-NO5	Analog Inputs—bidirectional
—	10-13	NO4B-NO1B	Analog Inputs—bidirectional
13	14	V+	Positive Supply Voltage Input
14	15	GND	Ground

## Applications Information

### Operation with

### Supply Voltages Other than 15V

Using supply voltages less than  $\pm 15V$  will reduce the analog signal range. The MAX308/MAX309 switches operate with  $\pm 4.5V$  to  $\pm 20V$  bipolar supplies or with a  $+4.5V$  to  $+30V$  single supply. Connect V- to GND when operating with a single supply. Both device types can also operate with unbalanced supplies, such as  $+24V$  and  $-5V$ . The *Typical Operating Characteristics* graphs show typical on-resistance with  $20V$ ,  $15V$ ,  $10V$ , and  $5V$  supplies. (Switching times increase by a factor of two or more for operation at  $5V$ .)

### Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed  $+44V$ .

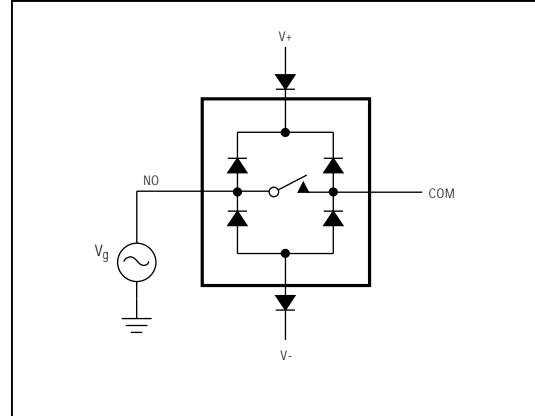


Figure 1. Overvoltage Protection Using External Blocking Diodes

# Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

## Test Circuits/Timing Diagrams

**MAX308/MAX309**

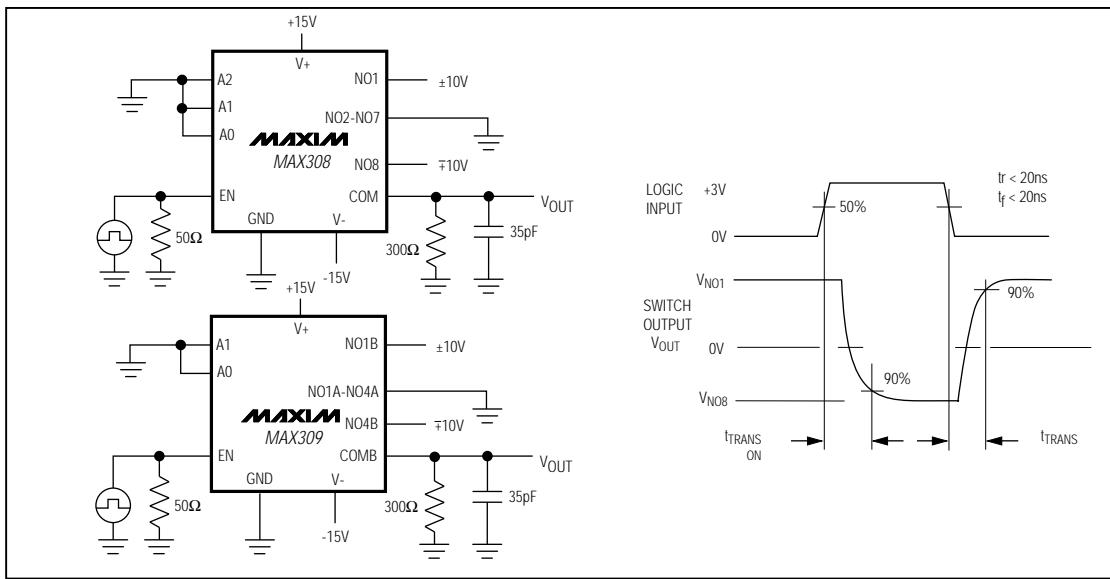


Figure 2. Transition Time

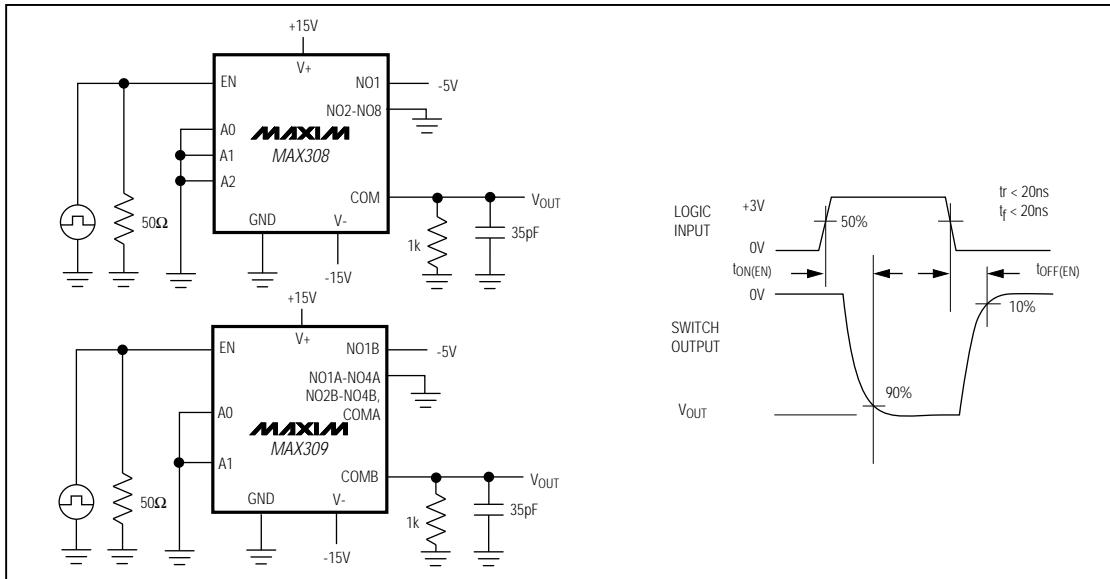


Figure 3. Enable Switching Time

## Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

### Test Circuits/Timing Diagrams (continued)

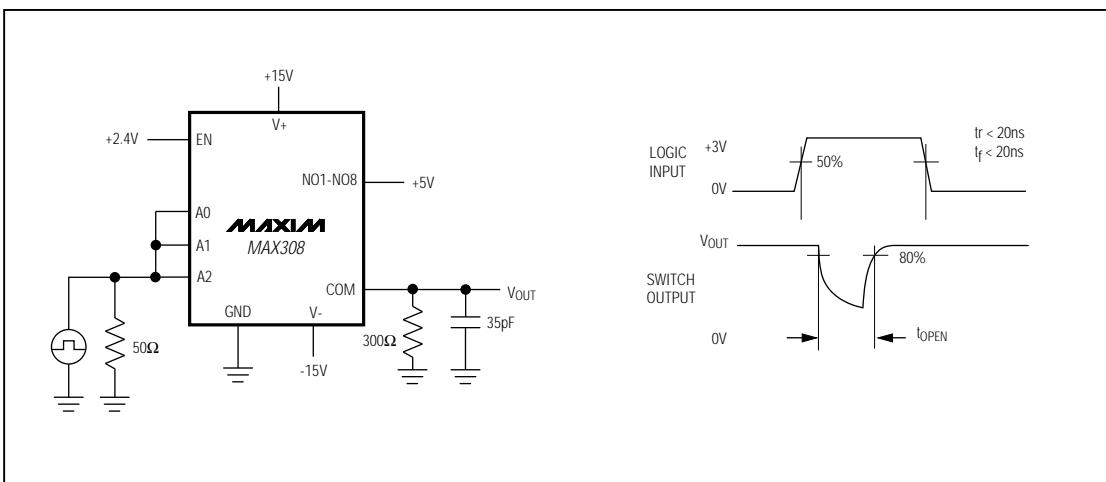


Figure 4. Break-Before-Make Interval

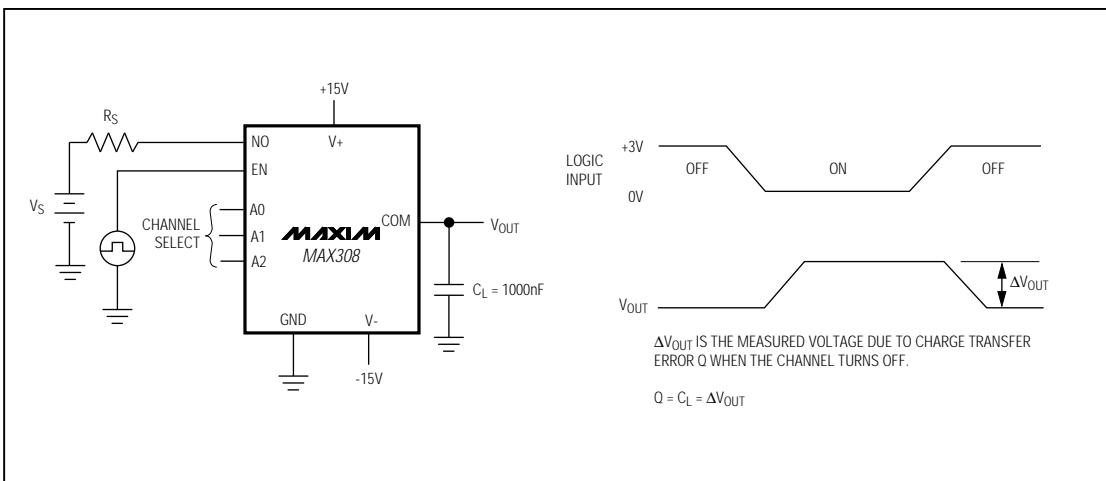


Figure 5. Charge Injection

## Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

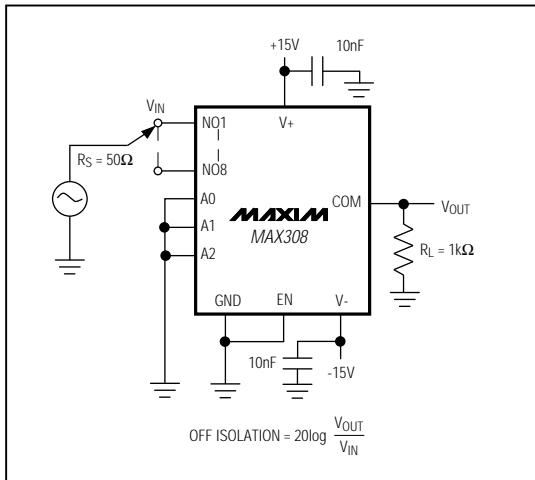


Figure 6. Off Isolation

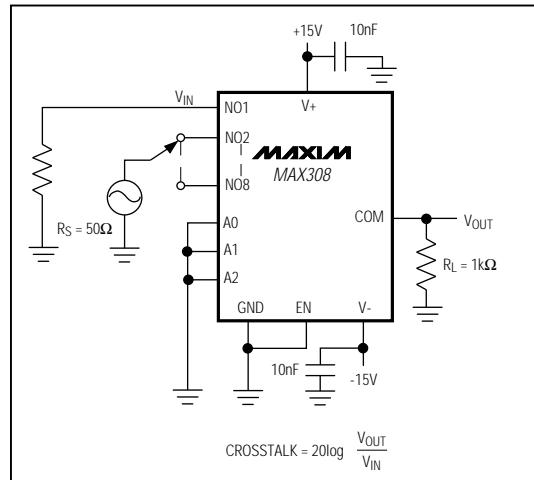


Figure 7. Crosstalk

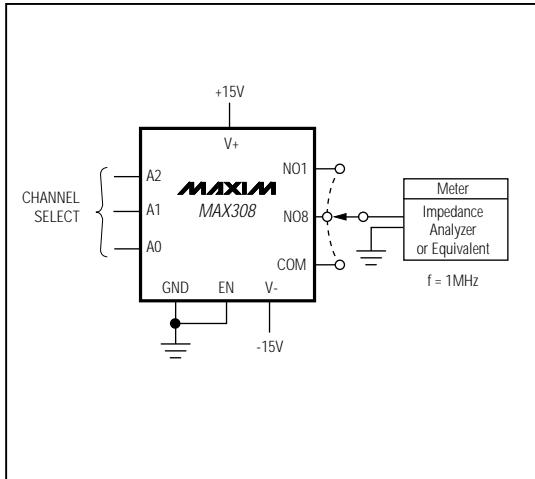
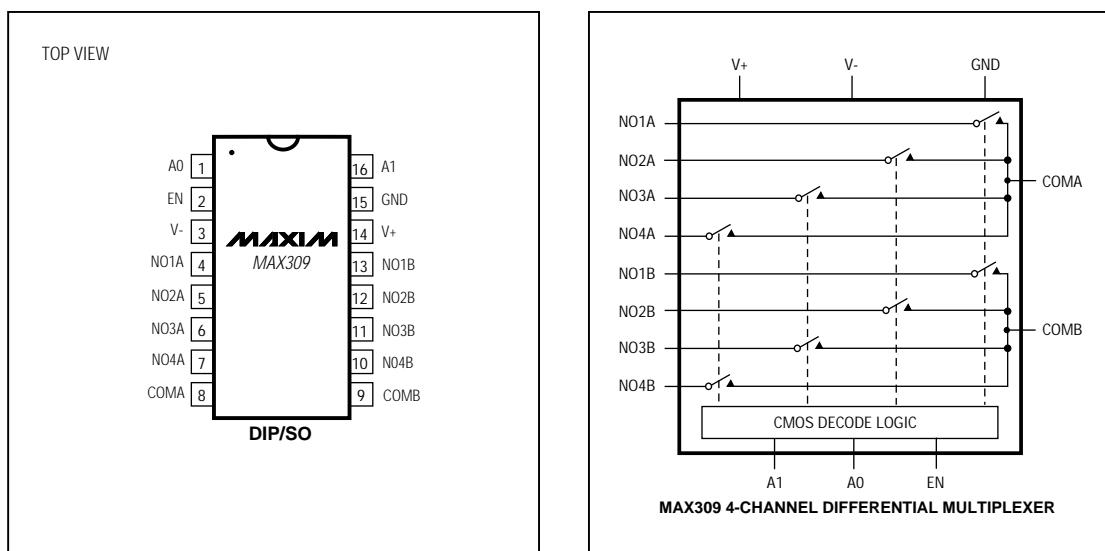


Figure 8. NO/COM Capacitance

*Precision, 8-Channel/Dual 4-Channel,  
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Pin Configurations/Functional Diagrams/Truth Tables (continued)



A2	A1	A0	EN	ON SWITCH
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

MAX308

LOGIC "0"  $V_{AL} \leq 0.8V$ , LOGIC "1"  $V_{AH} \geq 2.4V$

A1	A0	EN	ON SWITCH
X	X	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

MAX309

LOGIC "0"  $V_{AL} \leq 0.8V$ , LOGIC "1"  $V_{AH} \geq 2.4V$

Precision, 8-Channel/Dual 4-Channel,  
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*\_Ordering Information (continued)*

PART	TEMP. RANGE	PIN-PACKAGE
MAX309CPE	0°C to +70°C	16 Plastic DIP
MAX309CSE	0°C to +70°C	16 Narrow SO
MAX309C/D	0°C to +70°C	Dice*
MAX309EPE	-40°C to +85°C	16 Plastic DIP
MAX309ESE	-40°C to +85°C	16 Narrow SO
MAX309EJE	-40°C to +85°C	16 CERDIP
MAX309MJE	-55°C to +125°C	16 CERDIP**

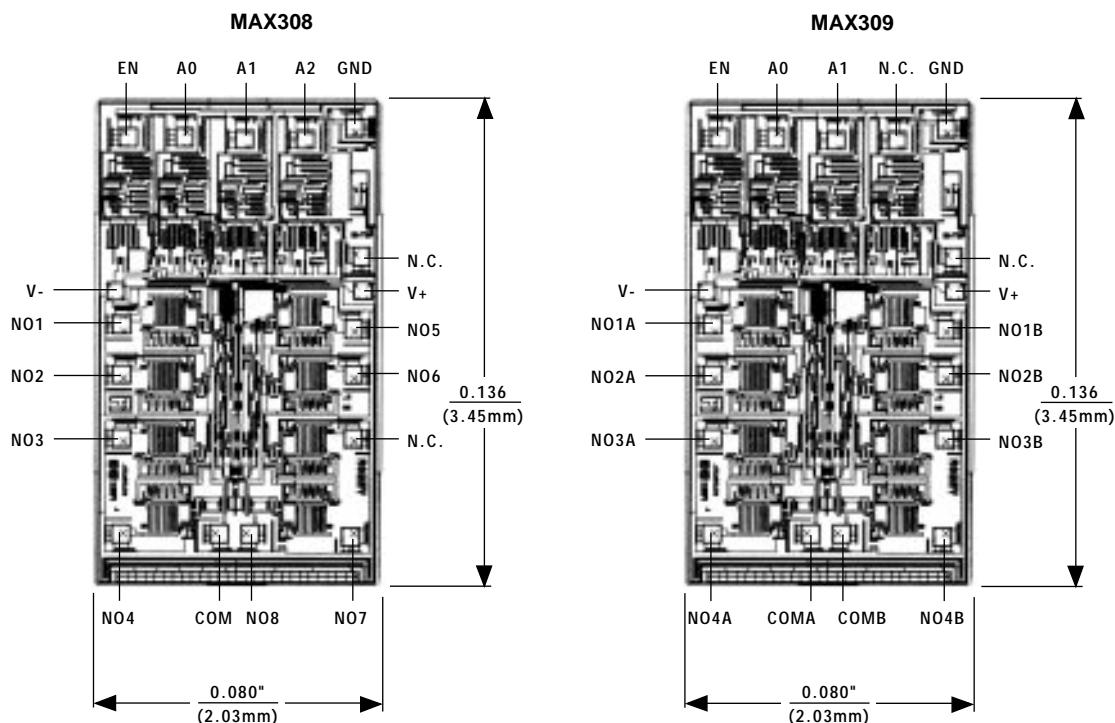
\* Contact factory for dice specifications.

\*\* Contact factory for availability.

# Precision, 8-Channel/Dual 4-Channel, High-Performance, CMOS Analog Multiplexers

MAX308/MAX309

## Chip Topographies



N.C. = NO INTERNAL CONNECTION

TRANSISTOR COUNT: 122  
SUBSTRATE CONNECTED TO V+

TRANSISTOR COUNT: 122  
SUBSTRATE CONNECTED TO V+

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